Perspectives in Graphene Research and Beyond



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Comprendre le monde, construire l'avenir



Disclaimer !

What I will not be talking about...

Applications of graphene

2013 : Graphene Flagship (10 Mrd Euros, European Union)

Potential applications: electronics, materials, optics, captors, energetics, medicine, environment,...

(very long list !)

→ https://en.wikipedia.org/wiki/Potential_applications_of_graphene

Real applications: tennis racquets

Applications [edit]

Main article: Potential applications of graphene

Graphene is a transparent and flexible conductor that holds great promise for various material/device applications, including solar cells, [276] light-emitting diodes (LED), touch panels, and smart windows or phones. [277] According to information from Changzhou, China-based 2D Carbon Graphene Material Co., Ltd &, graphene-based touch panel modules have been sold in volume to cell phone, wearable device, and home appliance manufacturers. For instance, smartphone products with graphene touch screens are already on the market.

In 2013, Head announced their new range of graphene tennis racquets.^[278]

As of 2015, there is one product available for commercial use: a graphene-infused printer powder.^[279] Many other uses for graphene have been proposed or are under development, in areas including electronics, biological engineering, filtration, lightweight/strong composite materials, photovoltaics and energy storage.^{[211][280]} Graphene is often produced as a powder and as a dispersion in a polymer matrix. This dispersion is supposedly suitable for advanced composites,^{[281][282]} paints and coatings, lubricants, oils and functional fluids, capacitors and batteries, thermal management applications, display materials and packaging, solar cells, inks and 3D-printers' materials, and barriers and films.^[283]

In 2016, researchers have been able to make a graphene film that can absorb 95% of light incident on it.^[284] It is also getting cheaper; recently scientists at the University of Glasgow have produced graphene at a cost that is 100 times less than the previous methods.^[285]

In August 2, 2016, BAC's new Mono model is said to be made out of graphene as a first of both a street-legal track car and a production car.^[286]



(a) The typical structure of a touch sensor in a touch panel. (Image courtesy of Synaptics, Incorporated.) (b) An actual example of 2D Carbon Graphene Material Co.,Ltd's graphene transparent conductor-based touchscreen that is employed in (c) a commercial smartphone.

Project-funding based research



https://www.nobelprize.org/nobel_prizes/physics/laureates/2005/hansch-slides.pdf

Graphene-based headphones



→ Project emerged from fundamental research at McGill University, Montréal

Fundamental condensed-matter research

Why do we care about graphene?

Prehistory: Graphene in a nutshell

- one-atom thick layer of graphite, isolated in 2004
- electronic conductor
- flexible membrane of exceptional mechanical stability
- Nobel Prize in Physics, 2010



Chuan Li, physique mésoscopique, LPS, Orsay

Interest for fundamental research:

"Quantum mechanics meets relativity in condensed matter" (electrons behave as 2D massless Dirac fermions)

Band structure of graphene

Dirac Hamiltonian (two *valleys* $\xi = \pm \sim$ fermion doubling)



Wave functions and winding numbers

wave function

$$\psi_{\xi,\lambda;\mathbf{q}} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1\\ \xi\lambda e^{-i\xi\phi_{\mathbf{q}}} \end{pmatrix} \quad \tan\phi_{\mathbf{q}} = \frac{q_y}{q_x}$$

winding number (\sim topol. charge)

$$W_{\xi,\lambda} = \frac{\xi\lambda}{2\pi} \oint_{C_i} \nabla_{\mathbf{q}} \phi_{\mathbf{q}} \cdot d\mathbf{q} = \xi\lambda$$

Phase of wave function (TRS-related Dirac points)

Time-reversal symmetry \rightarrow Dirac points have opposite winding number



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Since 2005: rewriting of the *theory of the electron liquid* for the case of graphene

- \rightarrow plasmonics
- \rightarrow electron-phonon coupling
- → superconductivity
- → electronic viscosity
- \rightarrow SU(4) FQHE/quantum-Hall ferromagnetism





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Since ~2006: other 2D materials hosting Dirac fermions

- \rightarrow organic materials
- → *tilted* Dirac cones
- → silicene...



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Since ~2006: other 2D crystals → semiconductors (transitionmetal dichalcogenides) → massive Dirac fermions (?)



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Since ~2010: heterostructures

- → bilayer graphene
- → BN encapsulation
- → band-structure engineering (?)



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 \rightarrow correlations and unconventional superconductivity







Since 2005: topological insulators and supercond.

- \rightarrow QAHE and QSHE
- → bulk-edge correspondence



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- Since ~2014: Weyl semimetals
- → 3D graphene
- → Fermi arcs→ chiral anomaly







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- Relativistic features of graphene electrons (beyond the spectrum)
- Massive Dirac fermions in 2D transition-metal dichalcogenides (TMDC)
- How to unveil geometry/topology in 2D materials (the role of Berry curvature)
- Future research: interplay between topology and correlations

Band structure of graphene

Tight-binding model (nearest-neighbour hopping) :

$$H_{\mathbf{k}} = \begin{pmatrix} \epsilon_0 & -t\gamma_{\mathbf{k}}^* \\ -t\gamma_{\mathbf{k}} & \epsilon_0 \end{pmatrix}$$

with (hopping from B to A) :

 $\gamma_{\mathbf{k}} = 1 + e^{i\mathbf{k}\cdot\mathbf{a}_1} + e^{i\mathbf{k}\cdot\mathbf{a}_2}$ *t* ~ 3 eV ~ 36 000 K Ehergy 3t ----electrons (CB) Energy 0 q_{x} qv K holes (VB) k_v -3tk_x



Band structure of gapped graphene

Tight-binding model (nearest-neighbour hopping) :

$$H_{\mathbf{k}} = \begin{pmatrix} \epsilon_0 + \Delta & -t\gamma_{\mathbf{k}}^* \\ -t\gamma_{\mathbf{k}} & \epsilon_0 - \Delta \end{pmatrix}$$

with (hopping from B to A) :

 $\gamma_{\mathbf{k}} = 1 + e^{i\mathbf{k}\cdot\mathbf{a}_1} + e^{i\mathbf{k}\cdot\mathbf{a}_2}$





energy bands :

$$E_{\lambda}(\mathbf{k}) = \epsilon_0 + \sqrt{t^2 |\gamma_{\mathbf{k}}|^2 + \Delta^2}$$

Berry curvature for insulating graphene



Berry curvature concentrated around Dirac points

Band structure of (gapped) graphene (continuum limit)

Continuum limit = series expansion in qa :

 $(E - E_{\text{Fermi}}) \ll t$ i.e. $qa = |\mathbf{k} - \mathbf{K}|a \ll 1$ $\rightarrow \gamma_{\mathbf{K}+\mathbf{q}} \simeq \gamma_{\mathbf{K}} + i\mathbf{q} \cdot \mathbf{a}_1 e^{2\pi/3} + i\mathbf{q} \cdot \mathbf{a}_2 e^{-2\pi/3}$ $\simeq \frac{3a}{2}(-q_x - iq_y)$ $\gamma_{-\mathbf{K}+\mathbf{q}} \simeq \gamma_{-\mathbf{K}} + i\mathbf{q} \cdot \mathbf{a}_1 e^{-2\pi/3} + i\mathbf{q} \cdot \mathbf{a}_2 e^{2\pi/3}$ $\simeq \frac{3a}{2}(q_x - iq_y)$ $\Delta = m v_F^2$ Dirac Hamiltonian (massive fermions) : ξ : valley index $H_{\xi}(\mathbf{q}) = \begin{pmatrix} \Delta & \hbar v_F(\xi q_x - iq_y) \\ \hbar v_F(\xi q_x + iq_y) & -\Delta \end{pmatrix} v_F = \frac{3at}{2^{\xi}}$

Landau levels (
$$\rightarrow$$
 magnetic field)

$$H_{\xi} = \begin{pmatrix} \Delta & \xi v(\Pi_{x} - \xi i \Pi_{y}) \\ \xi v(\Pi_{x} + i \xi \Pi_{y}) & -\Delta \end{pmatrix}$$
with (Peierls substitution):

$$\Pi_{x/y} = p_{x/y} + eA_{x/y}(\mathbf{r})$$

$$\Pi_{K} = \begin{pmatrix} \Delta & \sqrt{2}\frac{\hbar v}{l_{B}}a^{\dagger} \\ \sqrt{2}\frac{\hbar v}{l_{B}}a^{\dagger} & -\Delta \end{pmatrix}$$

$$H_{K'} = \begin{pmatrix} \Delta & -\sqrt{2}\frac{\hbar v}{l_{B}}a^{\dagger} \\ -\sqrt{2}\frac{\hbar v}{l_{B}}a^{\dagger} \\ -\sqrt{2}\frac{\hbar v}{l_{B}}a^{\dagger} \end{pmatrix}$$
fermions de Dirac massifs
Landau-level spectrum:

$$\epsilon_{\lambda,n\neq0}^{\xi} = \lambda \sqrt{\Delta^{2} + 2\hbar^{2}\frac{v^{2}}{l_{B}^{2}}n}$$

$$\sum_{\lambda} \left[\Delta + \hbar \frac{eB}{\Delta/v^{2}}n \right]$$

$$\epsilon_{n=0}^{\xi} = -\xi \Delta$$

$$\rightarrow parity anomaly$$
[Semenoff, PRL (1984)]

Dirac fermions in condensed matter

Are there relativistic signatures beyond the spectrum ?

→ Covariance

→ Coupling to electromagnetic field

2D electrons in crossed magnetic and electric fields

Hamiltonian for 2D electrons in crossed fields $\mathbf{B} = B\mathbf{u}_z = \nabla \times \mathbf{A}(\mathbf{r})$ and $\mathbf{E} = E\mathbf{u}_y$

 $H_0(\hbar \mathbf{q}) \to H_0(\mathbf{p} + e\mathbf{A}(\mathbf{r})) - eEy$

→ Non-relativistic (Schrödinger) fermions: Galilei transformation to comoving frame of reference with velocity $v_D = E/B$



$$\epsilon_{n,k_x} = \hbar \frac{eB}{m} \left(n + \frac{1}{2} \right) - \hbar v_D k_x$$



2D electrons in crossed magnetic and electric fields

Hamiltonian for 2D electrons in crossed fields $\mathbf{B} = B\mathbf{u}_z = \nabla \times \mathbf{A}(\mathbf{r})$ and $\mathbf{E} = E\mathbf{u}_y$

 $H_0(\hbar \mathbf{q}) \to H_0(\mathbf{p} + e\mathbf{A}(\mathbf{r})) - eEy$



2D electrons in crossed magnetic and electric fields



no electric field

2D electrons in crossed magnetic and electric fields



[Lukose et al., PRL (2007)]

Relativistic breakdown of Landau levels

Relativistic Landau levels:

$$\epsilon_{\pm n,k_x} = \pm \frac{\hbar v_F [1 - (v_D/v)^2]^{3/4}}{l_B} \sqrt{2n} - \hbar v_D k_x$$

Condition for drift velocity (upper critical electric field):

$$v_D = E/B < v \qquad \leftrightarrow \qquad E < E_c = vB$$

→ "magnetic regime" ~ existence of frame of reference with closed orbits

→ "electric regime" ~ open orbits in any frame of reference for

 $v_D > v \qquad \leftrightarrow \qquad E > vB$

Pseudo-covariance in tilted Dirac and Weyl cones

Generalised Dirac/Weyl Hamiltonian:

$$H_{\xi} = \xi \hbar v \left(q_x \sigma_x + \xi q_y \sigma_y + q_z \sigma_z \right) + \xi \hbar \mathbf{w}_0 \cdot \mathbf{q} \sigma_0$$

 \mathbf{W}_0 : tilt velocity σ_0 : 2x2 one matrix

Energy dispersion:

 $\epsilon_{\xi}(\mathbf{q}) = \xi \hbar \mathbf{w}_0 \cdot \mathbf{q} \pm \hbar v |\mathbf{q}|$



Criterion for maximal tilt

$$w_{0x}^2 + w_{0y}^2 + w_{0z}^2 < v^2$$

 $w_{0x}^2 + w_{0y}^2 + w_{0z}^2 > v^2$

type-I Dirac/Weyl semimetal

type-II Dirac/Weyl semimetal



Materials with tilted Dirac cones



→ Dirac semimetal under pressure

Katayama et al., JPSJ (2006)

Criterion for maximal tilt/relation with relativistic electrons in crossed fields

$$\tilde{w}_0 = (w_{0x}^2 + w_{0y}^2 + w_{0z}^2)/v^2 < 1 \qquad \tilde{w}_0 > 1$$

Pseudo-covariance in tilted Dirac and Weyl cones

Generalised Dirac/Weyl Hamiltonian (2D):

$$H_{\xi} = \xi \hbar v \left(q_x \sigma_x + \xi q_y \sigma_y + \tilde{w}_0 q_x \sigma_0 \right)$$

in a magnetic field:
$$A_x = -By$$
 $A_y = 0$

 $H_{\xi} = \xi \hbar v \left((q_x - eBy/\hbar)\sigma_x + \xi q_y \sigma_y + \tilde{w}_0 (q_x - eBy)\sigma_0 \right)$

covariant part

$$\begin{aligned} H_{\xi}^{cov} &= \xi \hbar v \left((q_x - eBy/\hbar) \sigma_x + \xi q_y \sigma_y \right) - eE_{\text{eff}} y \sigma_0 \\ E_{\text{eff}} &= w_0 B \quad \rightarrow \quad w_0 = v_D \quad : \text{ tilt = drift velocity } . \end{aligned}$$

Pseudo-covariance in tilted Dirac and Weyl cones: Landau levels

 $H_{\xi} = \xi \hbar v \left((q_x - eBy/\hbar)\sigma_x + \xi q_y \sigma_y + \tilde{w}_0 (q_x - eBy)\sigma_0 \right)$

Diagonalisation yields Landau-level spectrum: M.O.G. et al., Phys. Rev. B (2008)

$$\epsilon_{\pm n,q_x} = \pm \hbar \frac{v^*}{l_B} \sqrt{2n}$$

with renormalised velocity:

$$v^* = v[1 - (w_0/v)^2]^{3/4}$$

Pseudo-covariance in tilted Dirac and Weyl cones

 $\tilde{w}_0 < 1 \qquad \qquad \tilde{w}_0 > 1$

~ "magnetic" regime

~ "electric" regime

Pseudo-covariance in tilted Dirac and Weyl cones: Landau levels

 $H_{\xi} = \xi \hbar v \left((q_x - eBy/\hbar)\sigma_x + \xi q_y \sigma_y + \tilde{w}_0 (q_x - eBy)\sigma_0 \right)$

Diagonalisation yields Landau-level spectrum: M.O.G. et al., Phys. Rev. B (2008)

$$\epsilon_{\pm n,q_x} = \pm \hbar \frac{v^*}{l_B} \sqrt{2n}$$

with renormalised velocity:

$$v^* = v[1 - (w_0/v)^2]^{3/4}$$

Light-matter coupling

Motivation: **color shift** in relativity (*optical Doppler effect*)

→ Peierls substitution: $\mathbf{q} \rightarrow \mathbf{q} + \frac{e}{\hbar} [\mathbf{A}(\mathbf{r}) + \mathbf{A}_{rad}(t)]$ magnetic field radiation field → expansion of Hamiltonian to linear order in radiation field: $H(\mathbf{q}) \rightarrow H_B + e\mathbf{v} \cdot \mathbf{A}_{rad}(t)$

with velocity operator $\mathbf{v}=
abla_{\mathbf{q}}H(\mathbf{q})/\hbar$

 \rightarrow (magneto-)optical selection rules (matrix elements):

$$\psi^{\dagger}_{\lambda n} \mathbf{v} \psi_{\lambda' m}$$

Light-matter coupling

(magneto-)optical selection rules (matrix elements):

 $\psi^{\dagger}_{\lambda n} \mathbf{v} \psi_{\lambda' m}$

 \rightarrow graphene (no tilt, no electric field): $m = (n \pm 1)$

dipolar selection rules (in comoving frame):

 $\lambda n \to \lambda'(n+1)$ for right – handed light \circlearrowleft

 $\lambda n \to \lambda'(n-1)$ for left – handed light (

Infrared transmission spectroscopy in graphene

Grenoble high-field group: Sadowski et al., PRL 97, 266405 (2007)

ightarrow Lorentz boost in x direction, with $w_0=E_{
m eff}/B$ $ilde w_0=w_0/v$

 $x'^{\mu} = \Lambda^{\mu}_{\nu} x^{\nu} \qquad (vt', x') = (w_0 t + \tilde{w}_0 x) / \sqrt{1 - \tilde{w}_0^2}$

(Lorentz transformation of a 4-vector)

 \rightarrow transformation of wave function, with $\tanh \theta = \tilde{w}_0$:

 $\psi'(vt', x', y' = y) = S(\Lambda)\psi(vt, x, y)$ with $S(\Lambda) = e^{\theta\sigma_x/2}$

 \rightarrow selection rules known in co-moving frame

$$\psi_{\lambda n}^{\prime\dagger}\mathbf{v}\psi_{\lambda^{\prime}(n\pm1)}^{\prime}$$

WANTED: selection rules in lab frame !

• selection rules in comoving frame v_D (field E = 0)

 $\lambda n \to \lambda'(n \pm 1)$

 \Rightarrow new transitions in lab frame ($E \neq 0$)

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 $\lambda n \to \lambda'(n \pm 1)$

 \Rightarrow new transitions in lab frame ($E \neq 0$)

selection rules (absorbed frequencies) depend on frame of reference [Sári, MOG, Tőke, PRB 2015]

Pseudo-covariance in 3D Weyl semimetals

Novelty with respect to 2D:

Tilt direction no longer necessarily perpendicular to the magnetic field

→ magnetic and electric regimes no longer directly related to type-I and type-II Weyl semimetals

Pseudo-covariance in 3D Weyl semimetals

tilt parameter (vector)

$$\mathbf{t} = \left(\frac{w_{0x}}{w_x}, \frac{w_{0y}}{w_y}, \frac{w_{0z}}{w_z}\right)$$

inplane tilt parameter

$$\mathbf{t}_{\perp} = \frac{\mathbf{t} \times \mathbf{B}}{B} = \left(\frac{w_{0x}}{w_x}, \frac{w_{0y}}{w_y}\right)$$

 \Rightarrow Landau level quantisation if *B*-field "close" to tilt axis

 $|\sin \alpha| < 1/|\mathbf{t}|$

Pseudo-covariance in 3D Weyl semimetals – Landau levels

same recipe as for 2D: Lorentz boost to a frame of reference, where t_{\perp} vanishes

1D Landau bands

$$\epsilon_{\lambda,n}(k_z) = w_{0z}k_z + \lambda\sqrt{1-\beta^2}\sqrt{w_z^2k_z^2 + 2\frac{w_xw_y\sqrt{1-\beta^2}}{l_B^2}n}$$

where $\beta = |\mathbf{t}_{\perp}|$

3-dimensional Weyl semimetals	$ \mathbf{t}_{\perp} = \beta < 1$	$ \mathbf{t}_{\perp} = eta > 1$
$ \mathbf{t} < 1$	type-I WSM magnetic regime	type-I WSM electric regime ?
$ \mathbf{t} > 1$	type-II WSM magnetic regime	type-II WSM <i>electric</i> regime

Pseudo-covariance in 3D Weyl semimetals – Landau levels

Optical conductivity

Re
$$\sigma_{ll}(\omega) = \frac{\sigma_0}{2\pi l_B^2 \omega} \sum_{j,j'} |\mathbf{u}_l \cdot \mathbf{v}_{j,j'}|^2 [f(\epsilon_j) - f(\epsilon_{j'})] \delta(\omega - \omega_{j,j'})$$

again: violation of dipolar selection rules

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Example of TMDC: Molybdenum Disulfide (MoS₂)

Cheiwchanchamnangij & Lambrecht, PRB (2012)

many ab initio calculations, here:

- 3 p orbitals per S, 5 d orbitals per Mo = 11 orbitals
- at K points: $|d_{3r^2-z^2}\rangle$ and $(|d_{xy}\rangle + i\xi |d_{x^2-y^2}\rangle)/\sqrt{2}$

Schrödinger or massive Dirac fermions ?

Schrödinger or massive Dirac fermions?

no Berry curvature

Berry curvature

Schrödinger or massive Dirac fermions ?

band masses: $1/m_{\lambda} = 1/m_{\lambda}^0 + 1/m_D$, Dirac mass: $m_D = \Delta/v_D^2$

Schrödinger or massive Dirac fermions ?

$$\mathcal{H}(\mathbf{q}) = \begin{pmatrix} \Delta + \frac{\hbar^2}{2m_{\rm el}^0} q^2 & \hbar v_D(q_x - iq_y) \\ \hbar v_D(q_x + iq_y) & -\Delta - \frac{\hbar^2}{2m_{\rm h}^0} q^2 \end{pmatrix}$$

band masses: $1/m_{\lambda} = 1/m_{\lambda}^0 + 1/m_D$, Dirac mass: $m_D = \Delta/v_D^2$

Landau levels

$$\epsilon_{\lambda,n} = \delta\omega n - \frac{\Omega}{2} + \lambda \sqrt{\left(\Delta + \Omega n - \frac{\delta\omega}{2}\right)^2 + \omega'^2 n}$$

three frequencies: $\Omega = eB/M$, $\delta\omega = eB/\mu$, $\omega' = \sqrt{2}v_D/l_B$ bare electron mass: $1/m_e^0 = 1/M + 1/\mu$

bare hole mass: $1/m_{\rm h}^0 = 1/M - 1/\mu$

spectrum in parabolic approximation:

 $\epsilon_{\lambda,n} = \lambda \left[\Delta + \hbar \omega_{\lambda} (n + \gamma_{\lambda}) \right], \qquad \omega_{\lambda} = eB/m_{\lambda}$

 \rightarrow Phase offset γ_{λ} no longer quantised ! [~ surface states of 3D TIs, Wright & MacKenzie, PRB (2013)] (pure Schrödinger: $\gamma = 1/2$, pure Dirac: $\gamma = 0$)

Landau levels

increasing "Diracness"

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Exciton spectrum in 2D TMDC

Hydrogen model of excitons:

Possible reasons for failure of 2D hydrogen model at small *n*

 more realistic interaction potential to take into account screening effects (→ Keldysh potential)

• **band-coupling** effects (\rightarrow **Berry curvature** $\Omega_{\alpha}(\mathbf{P})$) \rightarrow semiclassical equations of motion :

$$\dot{\mathbf{P}}_{j} = -\frac{\partial V(\mathbf{R})}{\partial \mathbf{R}_{j}} - e\dot{\mathbf{R}}_{j} \times \mathbf{B}$$
$$\dot{\mathbf{R}}_{j} = \frac{\partial E_{\alpha}(\mathbf{P})}{\partial \mathbf{P}_{j}} \left(-\frac{1}{\hbar} \dot{\mathbf{P}}_{j} \times \mathbf{\Omega}_{\alpha}(\mathbf{P}_{j}) \right)$$

Modified "single-band" Hamiltonian (*toolbox*)

• Hamiltonian:

 $H = H_0(\mathbf{p}) + V(\mathbf{r})$

• Generalised Peierls substitution:

$$\mathbf{p} \rightarrow \mathbf{p} + e\mathbf{A}$$
 $\mathbf{r} \rightarrow \mathbf{r} + \frac{1}{2\hbar} \mathbf{\Omega}_{\alpha} \times \mathbf{p}$

→ justification: reproduction (at linear order) of semiclassical equations of motion (Heisenberg)

 $H = H_0(\mathbf{p}) + V(\mathbf{r}) + \frac{e}{2\hbar} \frac{\partial H_0}{\partial \mathbf{p}} \cdot (\mathbf{B} \times \mathbf{r}) + \frac{1}{2\hbar} \left(\frac{\partial V}{\partial \mathbf{r}} \right) \cdot (\mathbf{\Omega}_{\alpha} \times \mathbf{p})$

Zero B field

interaction

• Linearised Hamiltonian:

Exciton Hamiltonian

• Hamiltonian in center-of-mass frame:

$$H_{exc} = E_g + \frac{\mathbf{p}^2}{2\mu} + V(r) + \frac{1}{2\hbar} \frac{\partial V}{\partial \mathbf{r}} \cdot [\mathbf{\Omega}(\mathbf{p}) \times \mathbf{p}] + \frac{1}{4} |\mathbf{\Omega}(\mathbf{p})| \nabla^2 V(\mathbf{r})$$
Hydrogenic part
Berry-curvature correction + Darwin term

• Exciton Berry curvature:

 $\Omega(\mathbf{p}) = \Omega_e(\mathbf{p}) - \Omega_h(-\mathbf{p}) \simeq 2\Omega_e(\mathbf{p}=0)$

Zhou et al., PRL (2015) Srivastava & Imamoglu, PRL (2015) Trushin et al., PRL (2018)

Exciton Hamiltonian (orders of magnitude)

• Hamiltonian in center-of-mass frame:

$$H_{exc} = E_g + \frac{\mathbf{p}^2}{2\mu} + V(r) + \frac{1}{2\hbar} \frac{\partial V}{\partial \mathbf{r}} \cdot [\mathbf{\Omega}(\mathbf{p}) \times \mathbf{p}] + \frac{1}{4} |\mathbf{\Omega}(\mathbf{p})| \nabla^2 V(\mathbf{r})$$

Hydrogenic part

Berry-curvature correction + Darwin term

$$\sim \operatorname{Ry}^{*} = 13 \operatorname{eV} \times \frac{\mu}{m_{0}} \frac{1}{\kappa^{2}} \qquad \sim \operatorname{Ry}^{*} \times \left(\frac{\lambda_{C}}{a_{B}}\right)^{2} = \alpha^{2} \operatorname{R}$$

$$a_{B} = \hbar^{2} \kappa / \mu e^{2} \sim 5 \operatorname{\AA} \qquad \text{(effective Bohr radius)}$$

$$\lambda_{C} = \sqrt{\Omega} \leq \hbar / \sqrt{E_{g}} \mu = \alpha a_{B} \qquad \text{(effective Compton length)}$$

$$\alpha = (e^{2} / \hbar \kappa) \sqrt{\mu / E_{g}} \simeq 1 \qquad \text{("fine-structure constant")}$$

Exciton spectrum (Berry + Keldysh)

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Berry curvature – band projection

$$\mathcal{B}_{n}^{\sigma}(\mathbf{k}) = i\epsilon^{\sigma\mu\nu} \sum_{m \neq n} \frac{\langle u_{n} | \partial_{k_{\mu}} H(\mathbf{k}) | u_{m} \rangle \langle u_{m} | \partial_{k_{\nu}} H(\mathbf{k}) | u_{n} \rangle}{[E_{n}(\mathbf{k}) - E_{m}(\mathbf{k})]^{2}}$$

$$\rightarrow \text{ link to perturbation theory :}$$

$$u_{n}(\mathbf{k} + d\mathbf{k}) \rangle = |u_{n}(\mathbf{k}) \rangle + \sum_{m \neq n} |u_{m}(\mathbf{k})\rangle \frac{\langle u_{m}(\mathbf{k}) | d\mathbf{k} \cdot \nabla_{\mathbf{k}} H | u_{n}(\mathbf{k}) \rangle}{E_{n}(\mathbf{k}) - E_{m}(\mathbf{k})}$$

$$\stackrel{\text{Brillouin zone}}{\overbrace{k_{0}}} \bigvee_{k(t)} \underbrace{\mathsf{C}_{n}^{(k)}}_{\overbrace{m}^{(k)}} \underbrace{\mathsf{C}_{n}^{(k)}}_{\overbrace{m}^{(k)}} \underbrace{\mathsf{C}_{n}^{(k)}}_{\overbrace{m}^{(k)}} \underbrace{\mathsf{C}_{n}^{(k)}}_{\overbrace{m}^{(k)}} \underbrace{\mathsf{C}_{n}^{(k)}}_{n} \underbrace{\mathsf{C}_{n}^{(k)}}_{n}$$

1) QSHE insulator (+weak correlations)

1) QSHE insulator \rightarrow Mott insulator (AF, topologically trivial) ?

Fractional Chern insulator/quantum spin Hall effect

How does the (topo?) transition takes place from SHE to MI?

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